TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS III)

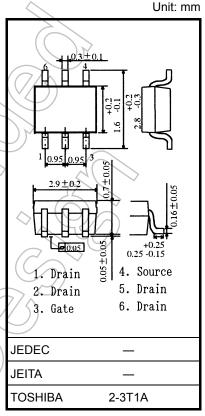
TPC6105

Notebook PC Applications Portable Equipment Applications

- Low drain-source ON resistance: $R_{DS (ON)} = 72 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance: |Y_{fs}| = 4.7 S (typ.)
- Low leakage current : $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -20 \text{ V)}$
- Enhancement mode : V_{th} = -0.5 to -1.2 V (V_{DS} = -10 V, I_D = -200 μA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | | Symbol | Rating | Unit | |
|--|-------|------------------------|--------------------|---------|--------------|--|
| Drain-source voltage | | | V_{DSS} | -20 | (\sqrt{v}) | |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | | V_{DGR} | -20 | V | |
| Gate-source voltage | | | V _{GSS} | ±8 | V | |
| Drain current | DC | (Note 1) | I _D | -2.7 | A | |
| Drain current | Pulse | (Note 1) | I _{DP} | -10.8 | A | |
| Drain power dissipation (t = 5 s) (Note 2a) | | | PD | 2.2 | W | |
| Drain power dissipation | | (t = 5 s) (Note 2b) | PD | 0.7 | W | |
| Single pulse avalanche energy (Note 3) | | | EAS | 1.2 | mJ | |
| Avalanche current | | | TAR | -1.35 | A | |
| Repetitive avalanche energy (Note 4) | | | EAR | 0.22 m | | |
| Channel temperature | | | 7/\T _{ch} | 150 | °C | |
| Storage temperature range | | | √ T _{stg} | -55~150 | ွင့ | |



Weight: 0.011 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

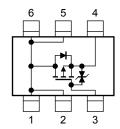
Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to ambient (t = 5 s) (Note 2a) | R _{th (ch-a)} | 56.8 | °C/W |
| Thermal resistance, channel to ambient (t = 5 s) (Note 2b) | R _{th (ch-a)} | 178.5 | °C/W |

Note: (Note 1), (Note 2), (Note 3) and (Note 4): See the third page.

This transistor is an electrostatic-sensitive device. Please handle with caution.

Circuit Configuration



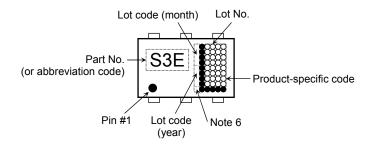
Electrical Characteristics (Ta = 25°C)

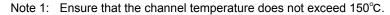
| Ch | aracteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|---------------|-----------------------|---|---------------|------|---------------|-----------|
| Gate leakage cui | rent | I _{GSS} | $V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±10 | μА |
| Drain cut-off curr | ent | I _{DSS} | $V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$ | | _ | -10 | μΑ |
| Drain-source breakdown voltage | | V _{(BR) DSS} | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -20 | _ | | V |
| | | V _{(BR) DSX} | $I_D = -10 \text{ mA}, V_{GS} = 8 \text{ V}$ | -12 | _ | | • |
| Gate threshold ve | oltage | V_{th} | $V_{DS} = -10 \text{ V}, I_D = -200 \mu\text{A}$ | 0.5 |) /_ | -1.2 | V |
| | | R _{DS} (ON) | $V_{GS} = -1.8 \text{ V}, I_D = -0.7 \text{ A}$ |) / /> | 215 | 300 | |
| Drain-source ON | resistance | R _{DS} (ON) | $V_{GS} = -2.5 \text{ V}, I_D = -1.4 \text{ A}$ | \rightarrow | 110 | 160 | $m\Omega$ |
| | | R _{DS} (ON) | $V_{GS} = -4.5 \text{ V}, I_D = -1.4 \text{ A}$ |) | 72 | 110 | |
| Forward transfer | admittance | Y _{fs} | $V_{DS} = -10 \text{ V}, I_D = -1.4 \text{ A}$ | 2.4 | 4.7 | | S |
| Input capacitance | | C _{iss} | | | 470 | _ | |
| Reverse transfer capacitance | | C _{rss} | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | | 70 | \rightarrow | pF |
| Output capacitance | | Coss | | - | 80 | > — | |
| Switching time | Rise time | t _r | VGS 5 V ID = -1.4 A | N N | 5 |) — | |
| | Turn-on time | t _{on} | | 7 | 9 | | ns |
| | Fall time | t _f | 4.7.2. 3. 4.7.2. 8. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. | | 8 | | 115 |
| | Turn-off time | t _{off} | V _{DD} ≃ −10 V Duty ≤ 1%, t _w = 10 μs | _ | 26 | | |
| Total gate charge (gate-source plus gate-drain) | | Qg | $V_{DD} \simeq -16 \text{ V}, V_{GS} = -5 \text{ V},$ | | 6 | 1 | |
| Gate-source charge | | Qgs | $I_D = -2.7 \text{ A}$ | _ | 4 | _ | nC |
| Gate-drain ("miller") charge | | Q _{gd} | | | 2 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Charact | eristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------------|----------------|--------------------|---|-----|------|-------|------|
| Drain reverse current | Pulse (Note 1) |) I _{DRP} | - | _ | _ | -10.8 | Α |
| Forward voltage | (diode) | V_{DSF} | $I_{DR} = -2.7 \text{ A}, V_{GS} = 0 \text{ V}$ | _ | _ | 1.2 | V |

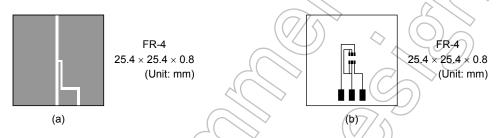
Marking (Note 5)





Note 2: (a) Device mounted on a glass-epoxy board (a) (t 5 s)

(b) Device mounted on a glass-epoxy board (b) (t = 5 s)



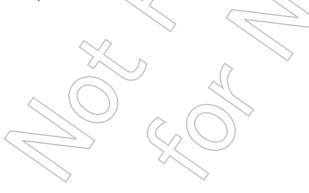
- Note 3: $V_{DD} = -16 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 0.5 mH, $R_G = 25 \Omega$, $I_{AR} = -1.35 \text{A}$
- Note 4: Repetitive rating: pulse width limited by maximum channel temperature
- Note 5: on the lower left of the marking indicates Pin 1.
- Note 6 A dot marking identifies the indication of product Labels.

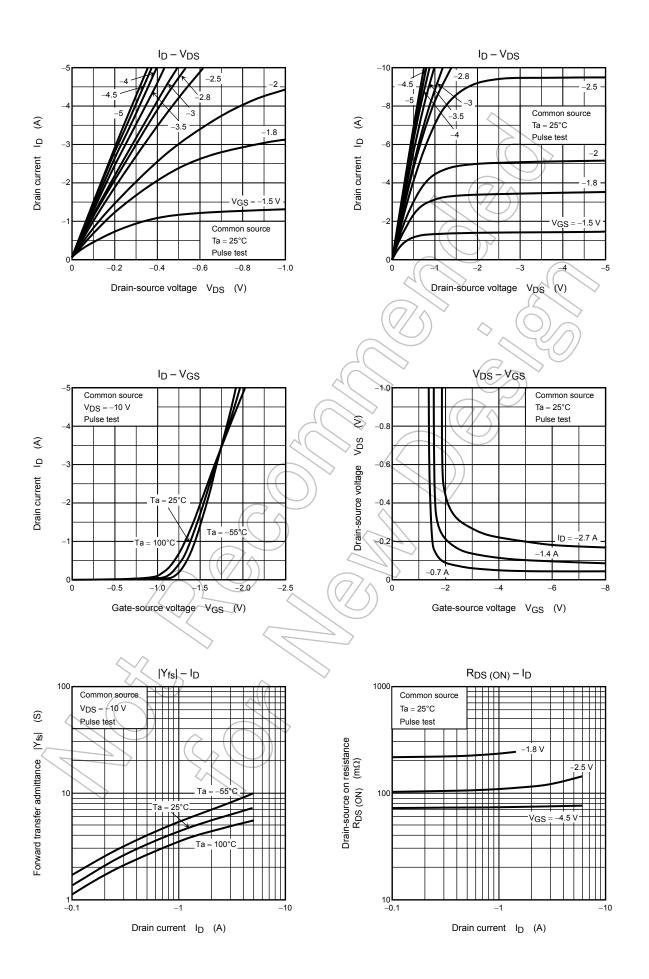
Without a dot: [[Pb]]/INCLUDES > MCV

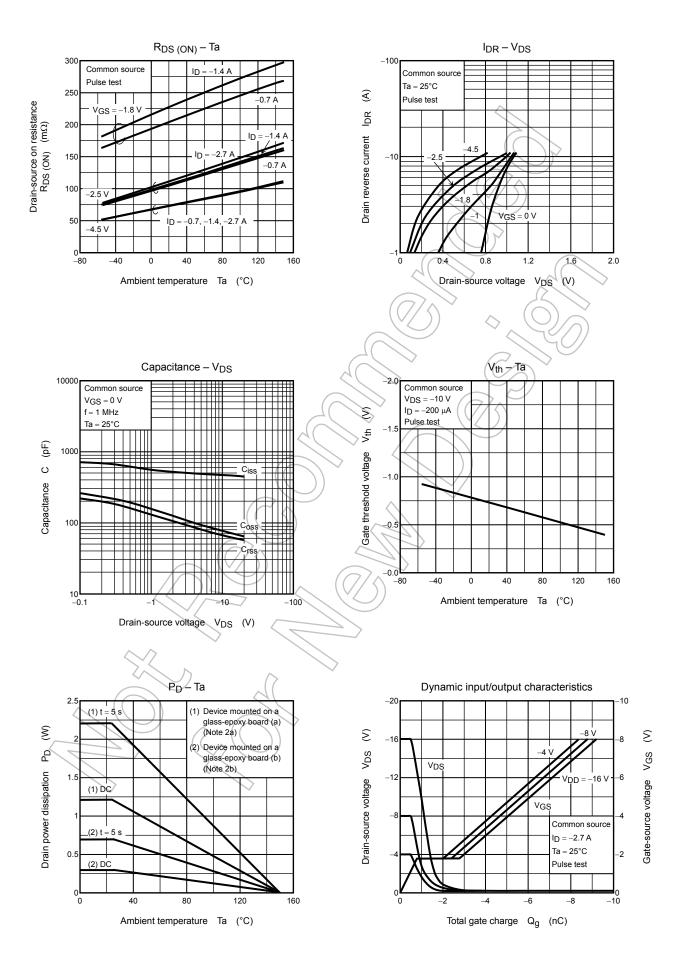
With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

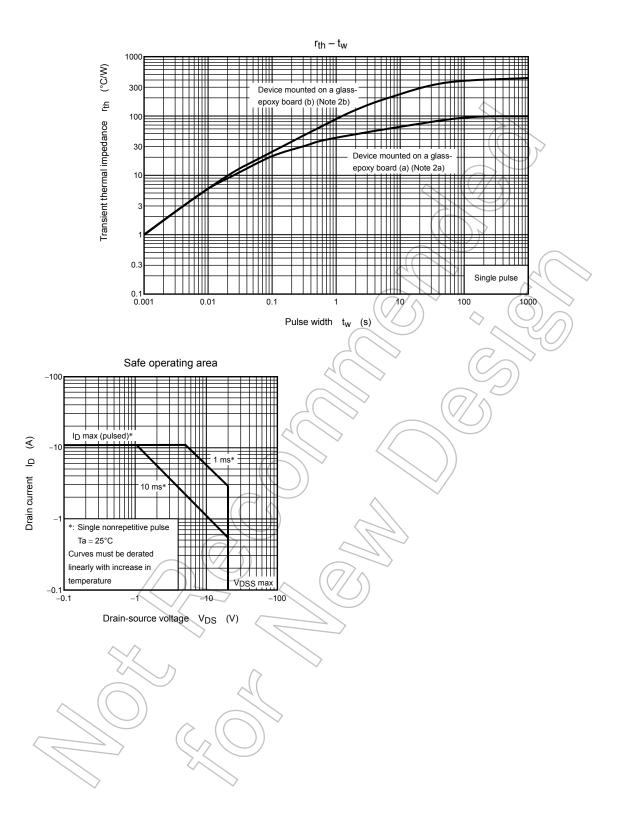
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